5 V, SUPER MINIMOLD WIDEBAND SI RFIC AMPLIFIER

FEATURES

- HIGH DENSITY SURFACE MOUNTING: 6 pin super minimold or SOT-363 package
- HIGH GAIN: 15 dB TYP
- SATURATED OUTPUT POWER: +10 dBm
- WIDEBAND RESPONSE: fu = 2.9 GHz TYP
- SUPPLY VOLTAGE: VCC = 4.5 to 5.5 V

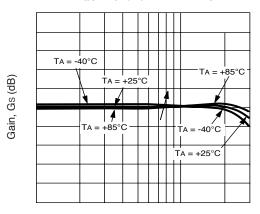
DESCRIPTION

NEc's UPC2708TB is a Silicon RFIC manufactured using the NESAT III process. This device is suitable as buffer amplifier for DBS, PCS and other communication receivers. The UPC2708TB is pin compatible and has comparable performance as the larger UPC2708T, so it is suitable for use as a replacement to help reduce system size. The IC is housed in a 6 pin super minimold or SOT-363 package.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

GAIN vs. FREQUENCYand TEMPERATURE

UPC2708TB



Frequency, f (GHz)

	PART NUMBER PACKAGE OUTLINE		UPC2708TB \$06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	MAX
Icc	Circuit Current (no signal)	mA	20	26	33
Gs	Small Signal Gain	dB	13	15	18.5
fU	Upper Limit Operating Frequency (The gain at 0.1 GHz)	GHz	2.7	2.9	
ΔGs	Gain Flatness, f = 0.1 - 2.6 GHz	dB		±0.8	
PSAT	Saturated Output Power	dBm	+7.5	+10	
P1dB	Output Power at 1 dB Compression Point	dBm		+7.5	
NF	Noise Figure	dB		6.5	8
RLIN	Input Return Loss	dB	8	11	
RLOUT	Output Return Loss	dB	16	20	
ISOL	Isolation	dB	18	23	
ΔGT	Gain-Temperature Coefficient	dB/°C		+0.002	
Rтн	Thermal Resistance (Junction to Ambient)	°C/W			325

ELECTRICAL CHARACTERISTICS (TA = 25 °C, f = 1 GHz, Vcc = 5 V)



ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

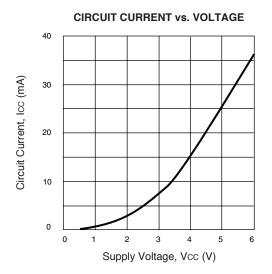
PARAMETERS	UNITS	RATINGS
Supply Voltage	V	6
Input Power	dBm	+10
PT Power Dissipation ²		200
Operating Temperature	°C	-40 to +85
TSTG Storage Temperature		-55 to +150
	Input Power Power Dissipation ² Operating Temperature	Input Power dBm Power Dissipation ² mW Operating Temperature °C

Notes:

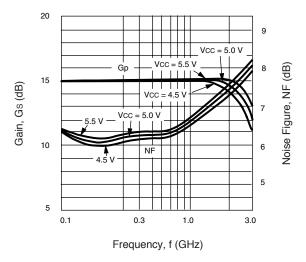
1. Operation in excess of any one of these parameters may result in permanent damage.

2. Mounted on 50 x 50 x 1.6 mm epoxy glass PWB (TA = $+85^{\circ}$ C).

TYPICAL PERFORMANCE CURVES (TA = 25°C)

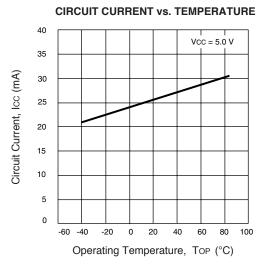


GAIN AND NOISE FIGURE vs. FREQUENCY AND VOLTAGE

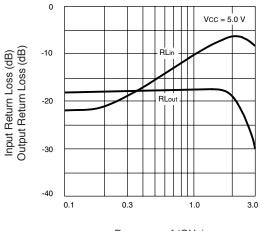


RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	UNITS	MIN	ТҮР	MAX
Vcc	Supply Voltage	V	4.5	5.0	5.5



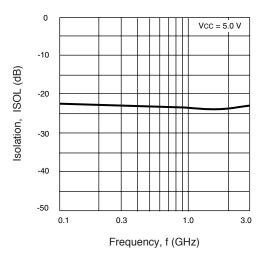
INPUT RETURN LOSS, OUTPUT RETURN LOSS vs. FREQUENCY



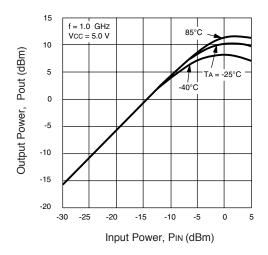
Frequency, f (GHz)

TYPICAL PERFORMANCE CURVES (TA = 25°C)

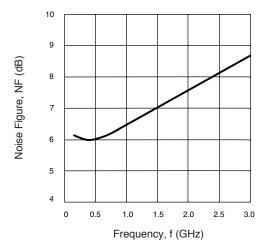
ISOLATION vs. FREQUENCY



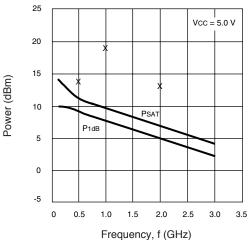
OUTPUT POWER vs. INPUT POWER AND TEMPERATURE



NOISE FIGURE vs. FREQUENCY

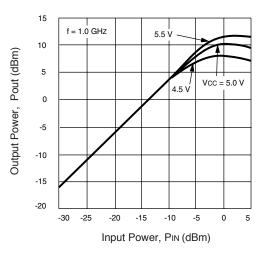


POWER vs. FREQUENCY

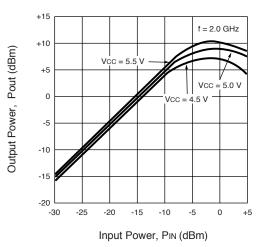


X: Typical SSB Third Order intercept Point

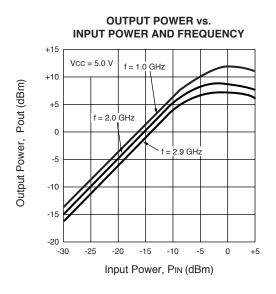
OUTPUT POWER vs. INPUT POWER AND VOLTAGE

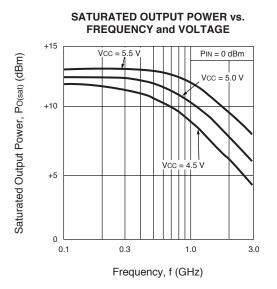


OUTPUT POWER vs. INPUT POWER AND VOLTAGE

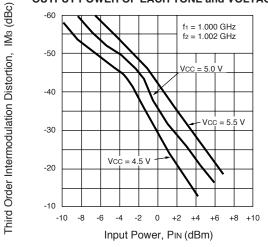


TYPICAL PERFORMANCE CURVES (TA = 25°C)

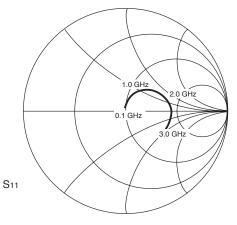


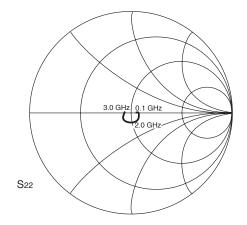


THIRD ORDER INTERMODULATION DISTORTION vs. OUTPUT POWER OF EACH TONE and VOLTAGE



TYPICAL SCATTERING PARAMETERS (TA = 25°C, VCC = VOUT = 5.0 V)





UPC2708TB

Vcc = Vout = 5 V, Icc = 27 mA

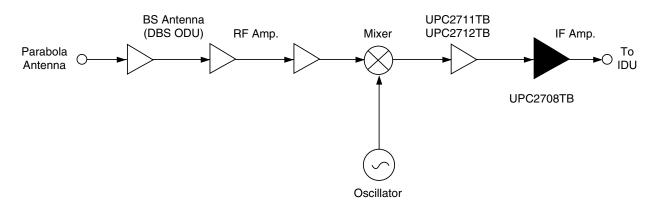
FREQUENCY	S	S 11	S	21	S 1	2	:	S22	к	
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		
0.1	0.039	138.9	5.815	-4.8	0.077	-0.8	0.051	0.9	1.34	
0.2	0.053	119.7	5.822	-9.8	0.075	-1.5	0.048	1.4	1.36	
0.3	0.069	106.7	5.815	-14.3	0.074	-0.6	0.049	5.9	1.38	
0.4	0.088	97.2	5.813	-18.8	0.074	-0.5	0.054	8.9	1.36	
0.5	0.105	91.6	5.794	-23.8	0.072	-1.1	0.054	8.8	1.39	
0.6	0.123	84.9	5.823	-28.4	0.071	-0.6	0.056	10.4	1.40	
0.7	0.144	79.7	5.871	-33.0	0.070	0.1	0.060	11.5	1.40	
0.8	0.164	74.7	5.890	-38.2	0.071	0.5	0.065	11.6	1.37	
0.9	0.186	70.7	5.938	-42.8	0.073	2.3	0.072	11.1	1.34	
1.0	0.205	66.1	5.960	-47.6	0.070	4.4	0.082	5.6	1.31	
1.1	0.226	61.7	6.072	-52.7	0.069	5.0	0.091	-4.6	1.28	
1.2	0.245	57.7	6.097	-57.5	0.070	4.4	0.082	5.6	1.31	
1.3	0.263	53.7	6.174	-63.0	0.067	2.5	0.085	0.6	1.33	
1.4	0.286	48.6	6.275	-68.4	0.069	5.0	0.091	-4.6	1.28	
1.5	0.308	44.3	6.371	-74.3	0.070	5.4	0.092	-8.2	1.24	
1.6	0.328	40.7	6.419	-79.8	0.066	7.1	0.097	-12.6	1.26	
1.7	0.344	36.2	6.470	-85.9	0.067	5.6	0.096	-19.6	1.23	
1.8	0.364	31.0	6.555	-92.1	0.069	8.2	0.100	-23.9	1.18	
1.9	0.382	26.0	6.542	-98.3	0.070	8.4	0.092	-8.2	1.24	
2.0	0.395	21.2	6.570	-104.7	0.070	8.7	0.101	-38.9	1.13	
2.1	0.405	16.8	6.528	-111.3	0.070	10.1	0.100	-47.2	1.12	
2.2	0.417	11.8	6.527	-118.5	0.071	9.4	0.096	-57.2	1.09	
2.3	0.427	6.6	6.438	-124.7	0.072	9.5	0.098	-66.1	1.09	
2.4	0.431	2.2	6.336	-131.3	0.071	10.7	0.095	-76.5	1.09	
2.5	0.431	-3.0	6.247	-138.1	0.072	12.8	0.098	-86.1	1.09	
2.6	0.434	-8.2	6.127	-145.0	0.071	15.4	0.094	-99.9	1.10	
2.7	0.423	-12.3	5.952	-151.7	0.071	14.5	0.088	-116.7	1.14	
2.8	0.419	-17.1	5.816	-158.2	0.070	16.1	0.081	-134.4	1.18	
2.9	0.408	-21.5	5.619	-165.0	0.073	15.3	0.074	-149.7	1.19	
3.0	0.400	-26.2	5.354	-171.5	0.074	17.1	0.065	-170.3	1.24	
3.1	0.386	-29.3	5.134	-177.4	0.075	17.1	0.053	172.8	1.28	

PIN DESCRIPTIONS

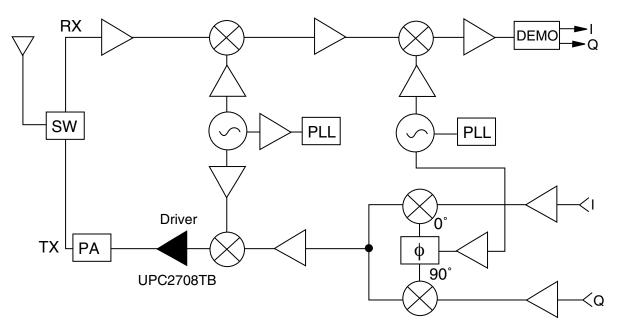
Pin No.	Symbol	Applied Voltage (V)	Pin Voltage (V)	Description	Internal Equivalent Circuit
1	Input	_	1.16	Signal input pin. An internal matching circuit, configured with resistors, enables 50Ω connection over a wide bandwidth. A multi-feedback circuit is designed to cancel the deviations of hFE and resistance. This pin must be coupled to the signal source with a blocking capacitor.	6 Vcc ≶ ↓ ₩ ↓ ○ O UT
4	Output		-	Signal output pin. Connect an inductor between this pin and Vcc to supply current to the internal output transistors.	
6	Vcc	4.5 to 5.5	_	Power supply pin. This pin should be externally equipped with a bypass capacitor to minimize ground impedance.	
2 3 5	GND	0	_	Ground pins. These pins should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to minimize impedance difference.	2, 3, 5

SYSTEM APPLICATION EXAMPLE

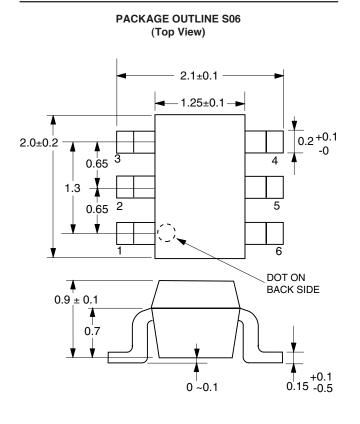
EXAMPLE OF DBS CONVERTERS



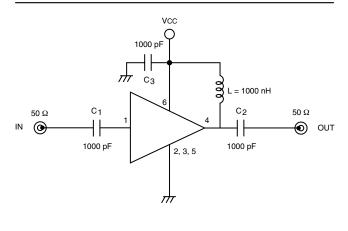
EXAMPLE OF 2.4 GHz BAND RECEIVER



OUTLINE DIMENSIONS (Units in mm)



TEST CIRCUIT



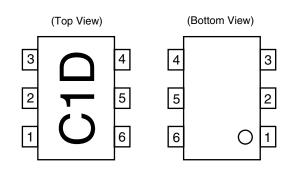
ORDERING INFORMATION

PART NUMBER	MARKING	QTY		
UPC2708TB-E3-A	C1D	3K/Reel		

Note:

Embossed Tape, 8 mm wide. Pins 1, 2 and 3 face perforated side of tape.

PIN CONNECTIONS



1. INPUT

- 2. GND
- GND
 OUTPUT
- 4. COTPO 5. GND
- 6. Vcc

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not De	etected	
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not De	etected	
РВВ	< 1000 PPM	Not De	etected	
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

See CEL Terms and Conditions for additional clarification of warranties and liability.

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